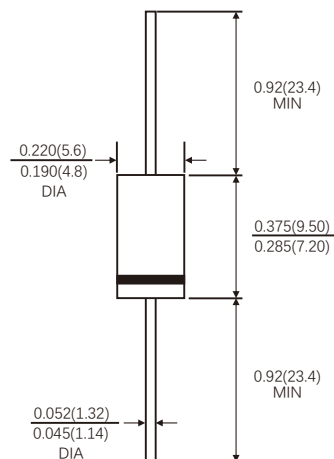
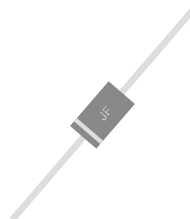


### FEATURES

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Metal silicon junction ,majority carrier conduction
- Guard ring for overvoltage protection
- Low power loss ,high efficiency
- High current capability ,low forward voltage drop
- High surge capability
- High temperature soldering guaranteed:260°C/10 seconds at terminals
- Component in accordance to RoHS 2011/65/EU



RoHS  
COMPLIANT



Dimensions in inches and (millimeters)

### MECHANICAL DATA

- Case: JEDEC DO-201AD molded plastic body
- Terminals: Plated axial leads, solderable per MIL-STD-750,method 2026
- Polarity: color band denotes cathode end
- Mounting Position: Any
- Weight: 0.041ounce, 1.15 grams

### TYPICAL APPLICATIONS

For use in low voltage ,high frequency inverters ,DC/DC converters,  
free wheeling ,and polarity protection applications

### MAXIMUM RATINGS

(Ratings at 25°C ambient temperature unless otherwise specified )

PRIMARY CHARACTERISTICS	
$I_F(AV)$	15.0A
$V_{RRM}$	100V
$I_{FSM}$	250A
$V_F$ at $I_F=15.0A, 25^\circ C$	0.76V
$T_{JMAX}$	150°C

Parameter	Symbol	Value	Unit
Maximum repetitive peak reverse voltage	$V_{RRM}$	100	V
Maximum average forward rectified current 0.375"(9.5mm) lead length(see fig.1)	$I_F(AV)$	15.0	A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method at rated $T_L$ )	$I_{FSM}$	250	A
Operating junction temperature range	$T_J$	-55 to+150	°C
Storage temperature range	$T_{stg}$	-55 to+150	°C

## ELECTRICAL CHARACTERISTICS (T<sub>A</sub>=25°C Unless otherwise noted)

Parameter	Test Conditions		Symbol	Typ.	Max.	Unit
Instaneous forward voltage	T <sub>A</sub> =25°C	I <sub>F</sub> =15.0A	V <sub>F</sub> <sup>1)</sup>	0.76	0.85	V
		I <sub>F</sub> =5.0A		0.64	-	
		I <sub>F</sub> =2.0A		0.54	-	
	T <sub>A</sub> =125°C	I <sub>F</sub> =15.0A		0.60	-	
		I <sub>F</sub> =5.0A		0.50	-	
		I <sub>F</sub> =2.0A		0.42	-	
Reverse current	T <sub>A</sub> =25°C	V <sub>R</sub> =100V	I <sub>R</sub> <sup>2)</sup>	0.8	5.0	μA
	T <sub>A</sub> =100°C			-	1.0	mA
	T <sub>A</sub> =125°C			-	5.0	
Typical junction capacitance	4V,1MHz		C <sub>J</sub>	420		pF
Reverse recovery time	I <sub>F</sub> =0.5A,I <sub>R</sub> =1A,I <sub>RR</sub> =0.25A <sup>3)</sup>			-	35	ns

Notes: 1.Pulse test: 300 μs pulse width,1% duty cycle

2.Pulse test: pulse width≤40ms

3.快恢复二极管trr测试条件。

## THERMAL CHARACTERISTICS

Parameter	Symbol	SR15100	Unit
Typical thermal resistance <sup>3)</sup>	R <sub>θJA</sub>	25.0	°C/W
	R <sub>θJL</sub>	5.0	

3.Thermal resistance from junction to lead vertical P.C.B. mounted , 0.375"(9.5mm)lead length

## AVAILABLE PACK INFORMATION

Product code	Pack	Box Size L*W*H(mm)	Quantity(pcs/box)	Carton SizeL*W*H(mm)	Quantity(box/carton)
SR15100-DO-201AD	B/P	190*80*21	200	433*203*230	50
SR15100-DO-201AD	T/B	255*77*125	1000	400*265*270	10

# RATINGS AND CHARACTERISTICS OF SR15100

FIG.1-FORWARD CURRENT DERATING CURVE

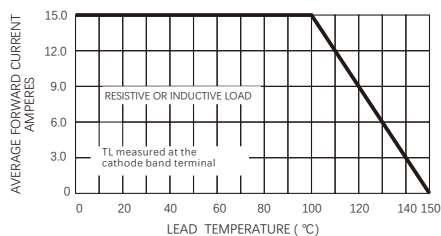


FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

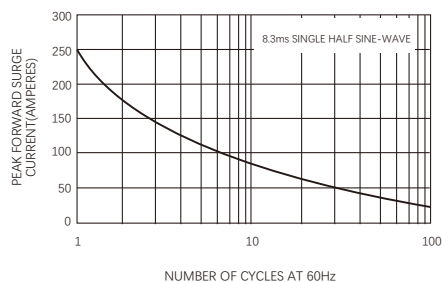


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

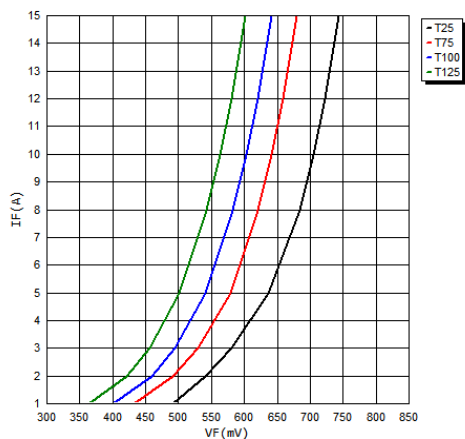


FIG.4-TYPICAL REVERSE CHARACTERISTICS

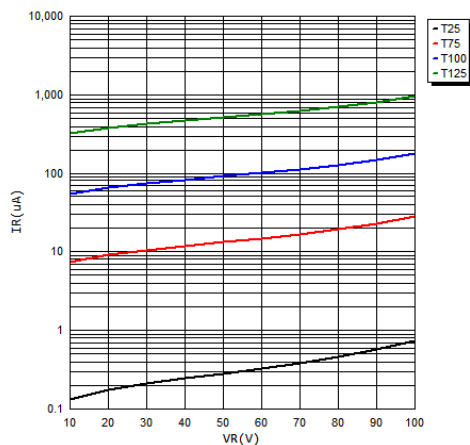
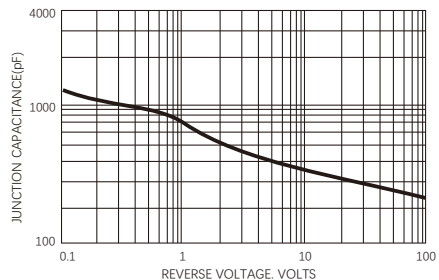


FIG.5-TYPICAL JUNCTION CAPACITANCE



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